

Description

The LY143EA05UL is a TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. It complies with IEC 61000-4-2 (ESD), $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a lead-free SOT-143 package. It is designed to protect components which are connected to high speed interfaces and transmission lines from voltage surges.

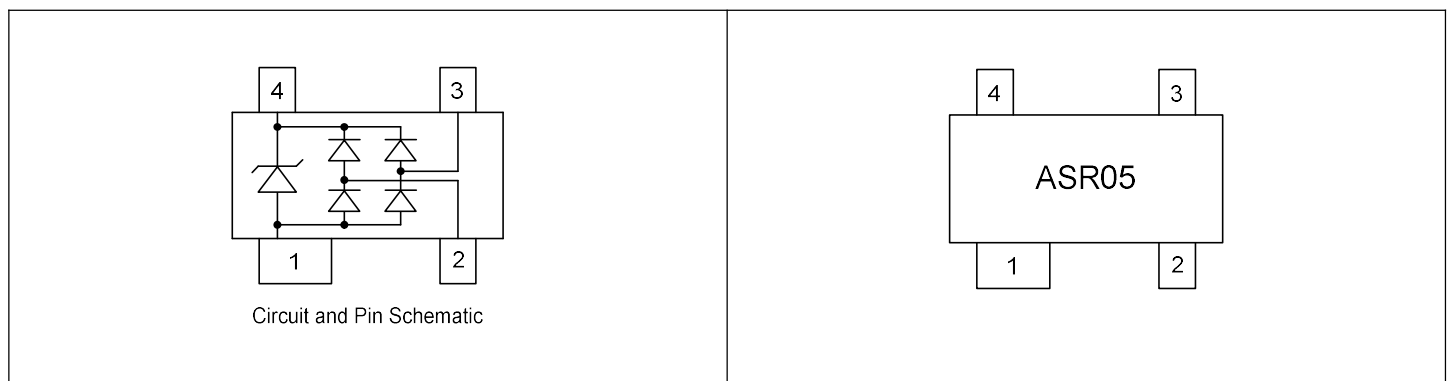
Features

- Low clamping voltage
- Ultra low leakage current
- Operating voltage: 5V
- RoHS compliant
- IEC-61000-4-2 ESD $\pm 30\text{kV}$ Air, $\pm 30\text{kV}$ Contact
- Packaging: 7 inch reel, 3000pcs/reel

Applications

- Wireless Systems
- LAN/WAN equipment
- Video Line Protection
- Portable Instrumentation
- High Speed Data Line
- I²C Bus Protection
- ISDN S/T Interface

Pin Configuration and Marking



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

| Parameter | Symbol | Value |
|--|-----------|---|
| Peak Pulse Power (8/20 μs) | P_{PP} | 400W |
| Peak Pulse Current (8/20 μs) | I_{PP} | 20A |
| ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact) | V_{ESD} | $\pm 30\text{kV}$ $\pm 30\text{kV}$ |
| Ambient Temperature Range | T_A | -55°C to $+125^\circ\text{C}$ |
| Storage Temperature Range | T_{STG} | -55°C to $+150^\circ\text{C}$ |

Electrical Characteristics ($T_A=25^\circ\text{C}$)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. |
|-------------------------|-----------|--|------|------|-------------------|
| Reverse Working Voltage | V_{RWM} | | - | - | 5V |
| Breakdown Voltage | V_{BR} | $I_T = 1\text{mA}$ | 6V | - | - |
| Reverse Leakage Current | I_R | $V_{RWM} = 5\text{V}$ | - | - | 0.5 μA |
| Clamping Voltage | V_C | $I_{PP} = 1\text{A}$ (8/20 μs) | - | - | 10V |
| | | $I_{PP} = 20\text{A}$ (8/20 μs) | - | - | 20V |
| Junction Capacitance | C_J | $V_R = 0\text{V}$, $f = 1\text{MHz}$, between I/O pins | - | - | 3pF |
| | | $V_R = 0\text{V}$, $f = 1\text{MHz}$, between I/O pins to ground | - | 3pF | 6pF |

Typical Characteristic Curves ($T_A=25^{\circ}\text{C}$)

Figure 1. Peak Pulse Power Rating Curve

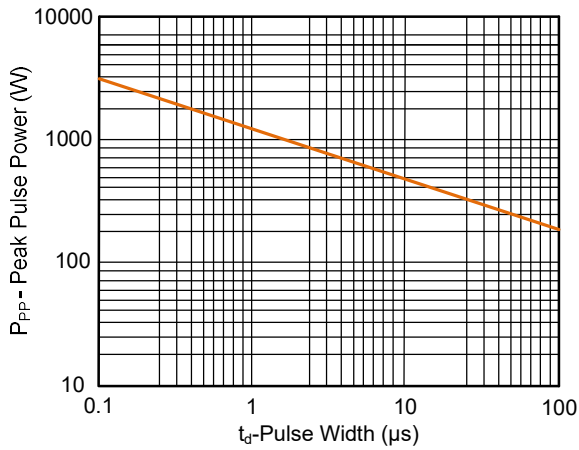


Figure 2. Pulse Derating Curve

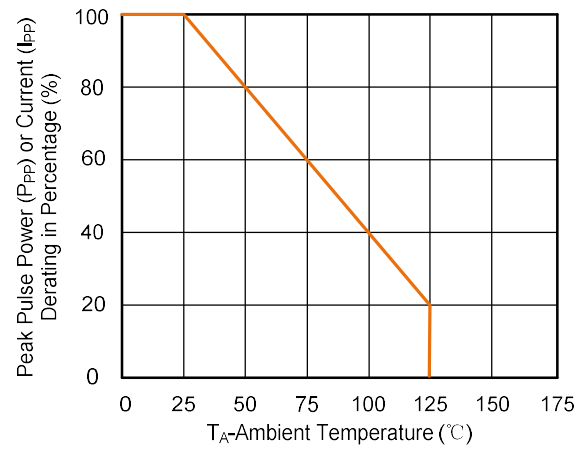


Figure 3. Clamping Voltage vs. Peak Pulse Current

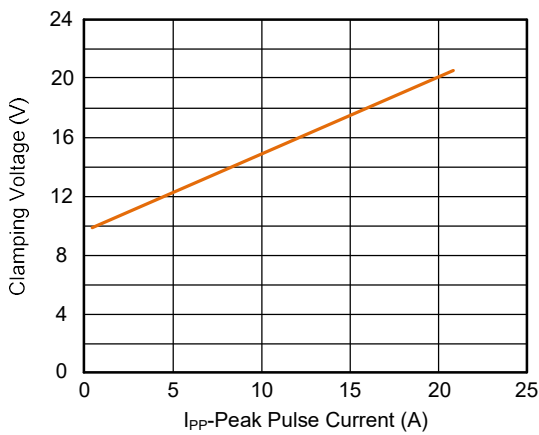


Figure 4. Junction Capacitance vs. Reverse Voltage

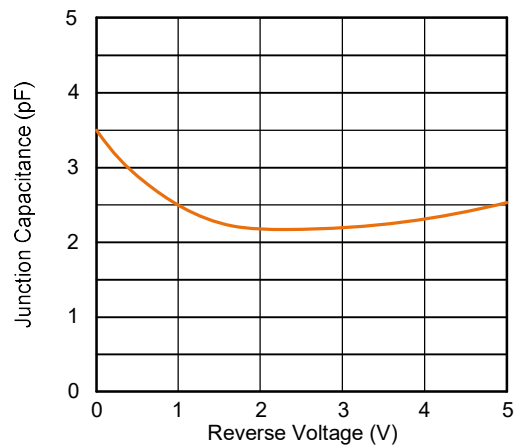


Figure 5. Pulse Waveform (8/20μs)

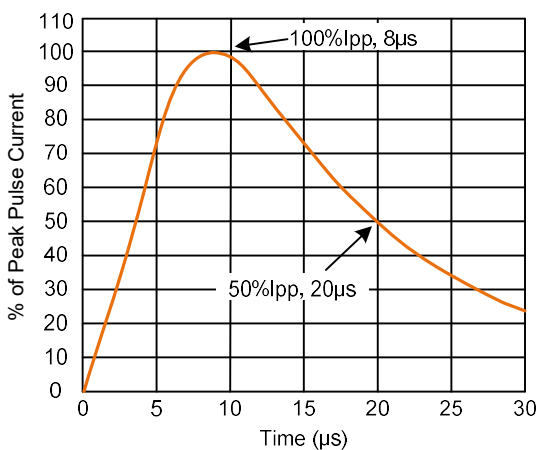
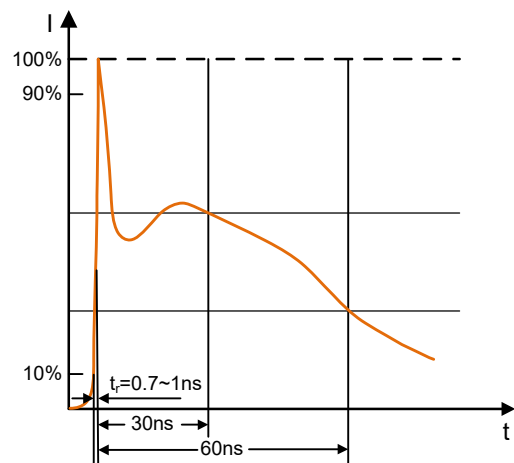
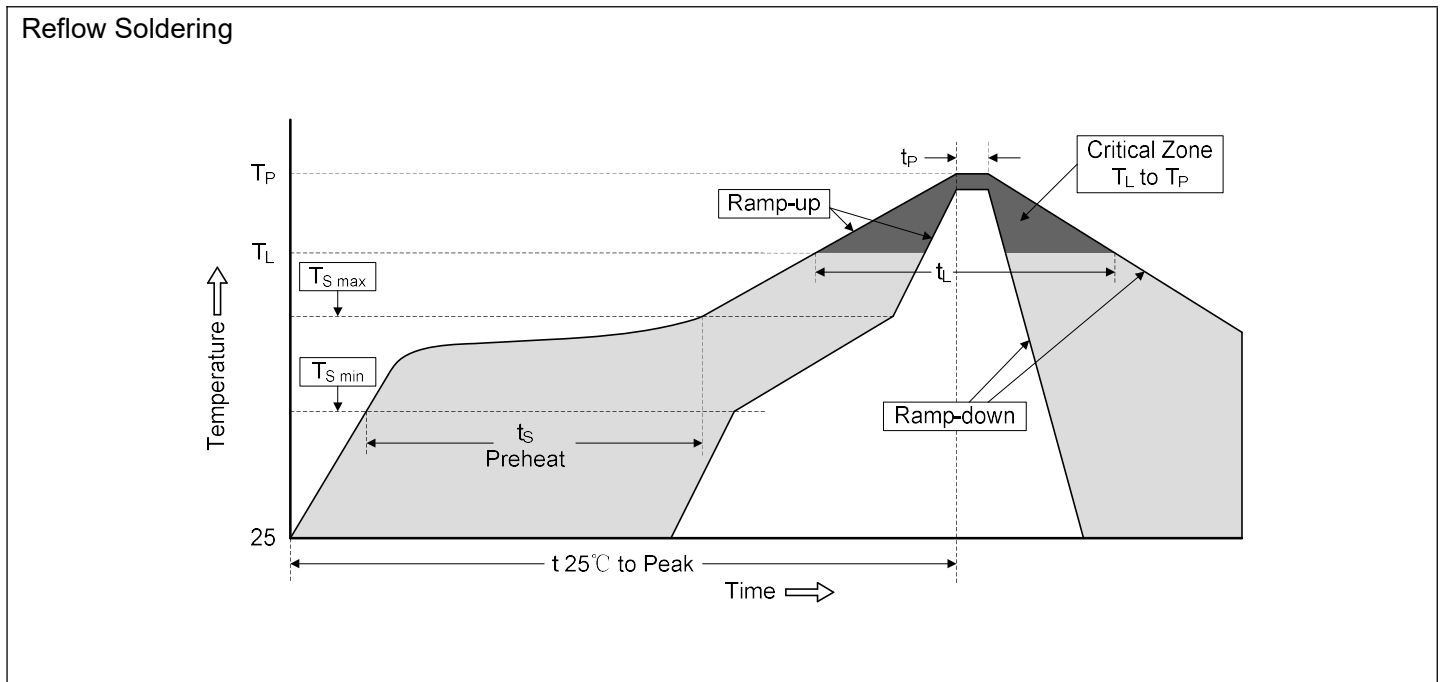


Figure 6. Pulse Waveform (IEC61000-4-2)



Soldering Parameters



| Profile Feature | Pb-Free Assembly |
|---|----------------------------------|
| Average ramp-up rate (T_L to T_P) | 3°C/second max. |
| Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s) | 150°C 200°C 60-180 seconds |
| $T_{S\ max}$ to T_L -Ramp-up Rate | 3°C/second max. |
| Time maintained above: -Temperature (T_L) -Time (t_L) | 217°C 60-150 seconds |
| Peak Temperature (T_P) | 260°C |
| Time within 5°C of actual Peak Temperature (t_p) | 20-40 seconds |
| Ramp-down Rate | 6°C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |

Dimensions (SOT-143)

